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FAIRCHILD SEMICONDUCTOR®

June 2013

FDMB3900AN

Dual N-Channel PowerTrench® MOSFET

25 V, 7.0 A, 23 mΩ

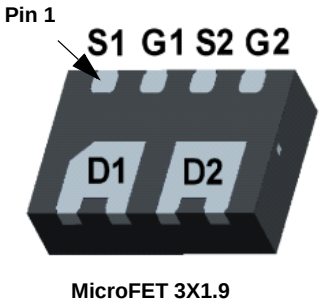
Features

- Max $r_{DS(on)}$ = 23 mΩ at V_{GS} = 10 V, I_D = 7.0 A
- Max $r_{DS(on)}$ = 33 mΩ at V_{GS} = 4.5 V, I_D = 5.5 A
- Fast switching speed
- Low gate charge
- High performance trench technology for extremely low $r_{DS(on)}$
- High power and current handling capability
- RoHS Compliant

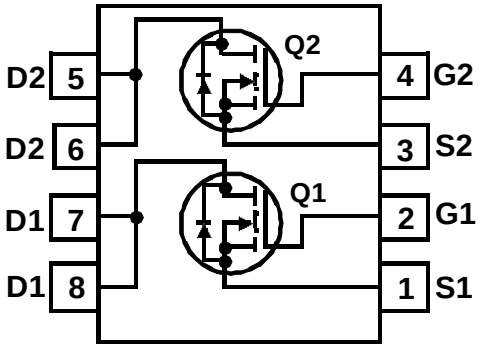
General Description

These N-Channel Logic Level MOSFETs are produced using Fairchild Semiconductor's advanced PowerTrench® process that has been especially tailored to minimize the on-state resistance and yet maintain superior switching performance.

These devices are well suited for low voltage and battery powered applications where the low in-line power loss and fast switching are required.



MicroFET 3X1.9



MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Parameter			Ratings	Units
V_{DS}	Drain to Source Voltage			25	V
V_{GS}	Gate to Source Voltage			±20	V
I_D	Drain Current -Continuous	T_A = 25 °C	(Note 1a)	7.0	A
	-Pulsed			28	
P_D	Power Dissipation	T_A = 25 °C	(Note 1a)	1.6	W
	Power Dissipation	T_A = 25 °C	(Note 1b)	0.8	
T_J, T_{STG}	Operating and Storage Junction Temperature Range			-55 to +150	°C

Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	80	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1b)	165	

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
3900	FDMB3900AN	MicroFET 3X1.9	7 ”	8 mm	3000 units

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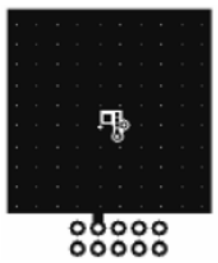
Electrical Characteristics T_J = 25 °C unless otherwise noted

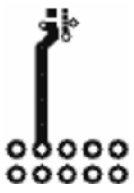
Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
Off Characteristics						
BV_{DSS}	Drain to Source Breakdown Voltage	I_D = 250 μA, V_{GS} = 0 V	25			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	I_D = 250 μA, referenced to 25 °C		17		mV/°C
I_{DSS}	Zero Gate Voltage Drain Current	V_{DS} = 20 V, V_{GS} = 0 V			1	μA
I_{GSS}	Gate to Source Leakage Current	V_{GS} = ±20 V, V_{DS} = 0 V			±100	nA
On Characteristics						
$V_{GS(th)}$	Gate to Source Threshold Voltage	V_{GS} = V_{DS}, I_D = 250 μA	1.0	2.0	3.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	I_D = 250 μA, referenced to 25 °C		-6		mV/°C
$r_{DS(on)}$	Static Drain to Source On Resistance	V_{GS} = 10 V, I_D = 7.0 A		19	23	mΩ
		V_{GS} = 4.5 V, I_D = 5.5 A		26	33	
		V_{GS} = 10 V, I_D = 7.0 A, T_J = 125 °C		26	32	
g_{FS}	Forward Transconductance	V_{DS} = 5 V, I_D = 7.0 A		27		S
Dynamic Characteristics						
C_{iss}	Input Capacitance	V_{DS} = 13 V, V_{GS} = 0 V, f = 1MHz		650	890	pF
C_{oss}	Output Capacitance			151	200	pF
C_{rss}	Reverse Transfer Capacitance			141	215	pF
R_g	Gate Resistance			0.8		Ω
Switching Characteristics						
$t_{d(on)}$	Turn-On Delay Time	V_{DD} = 13 V, I_D = 7.0 A, V_{GS} = 10 V, R_{GEN} = 6 Ω		6	12	ns
t_r	Rise Time			3	10	ns
$t_{d(off)}$	Turn-Off Delay Time			15	26	ns
t_f	Fall Time			3	10	ns
$Q_{g(TOT)}$	Total Gate Charge	V_{GS} = 0 V to 10 V, V_{DD} = 13 V, I_D = 7.0 A		11	17	nC
	Total Gate Charge	V_{GS} = 0 V to 5 V, V_{DD} = 13 V, I_D = 7.0 A		7	10	nC
Q_{gs}	Gate to Source Charge	V_{DD} = 13 V, I_D = 7.0 A		2.0		nC
Q_{gd}	Gate to Drain “Miller” Charge	V_{DD} = 13 V, I_D = 7.0 A		3.0		nC
Drain-Source Diode Characteristics						
V_{SD}	Source to Drain Diode Forward Voltage	V_{GS} = 0 V, I_S = 1.25 A (Note 2)		0.8	1.2	V
		V_{GS} = 0 V, I_S = 7.0 A (Note 2)		0.9	1.2	
t_{rr}	Reverse Recovery Time	I_F = 7.0 A, di/dt = 100 A/μs		14	24	ns
Q_{rr}	Reverse Recovery Charge			3	10	nC

NOTES:

1. $R_{\theta JA}$ is determined with the device mounted on a 1 in^2 pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.



a. 80 °C/W when mounted on a 1 in^2 pad of 2 oz copper



b.165 °C/W when mounted on a minimum pad of 2 oz copper

2. Pulse Test: Pulse Width < 300 μs, Duty cycle < 2.0 %.

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Typical Characteristics T_J = 25°C unless otherwise noted

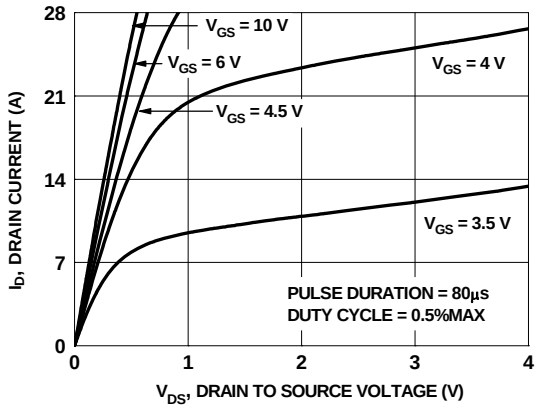

Figure 1. On-Region Characteristics

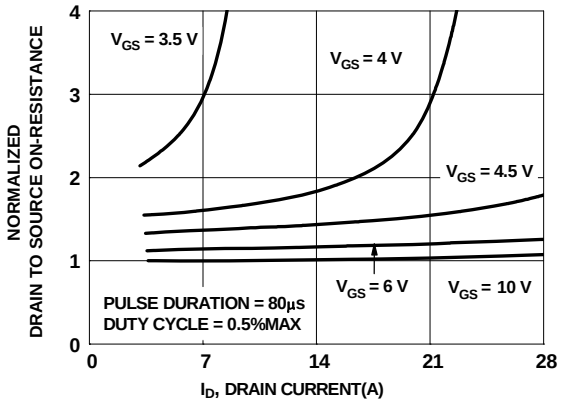

Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

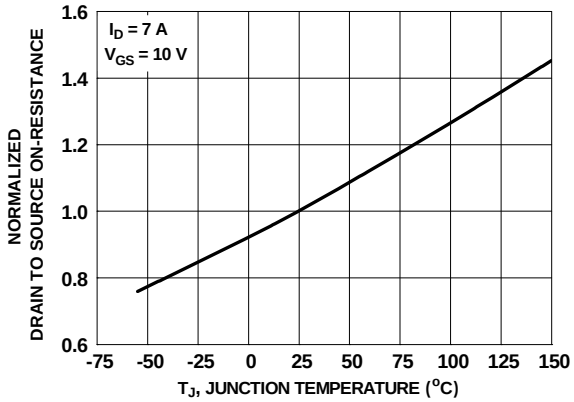

Figure 3. Normalized On-Resistance vs Junction Temperature

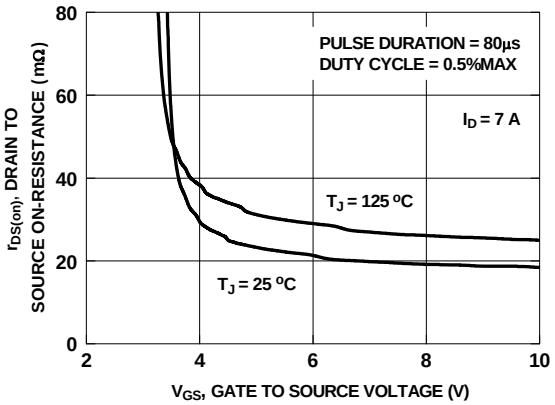

Figure 4. On-Resistance vs Gate to Source Voltage

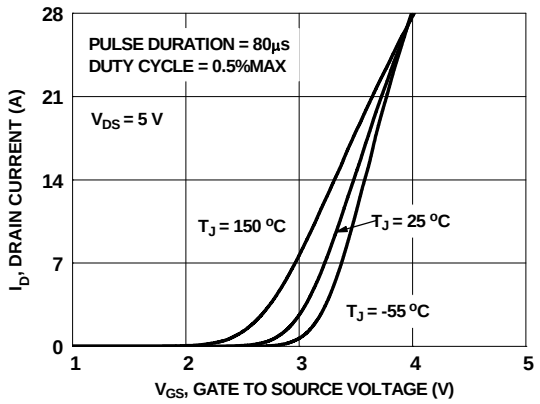

Figure 5. Transfer Characteristics

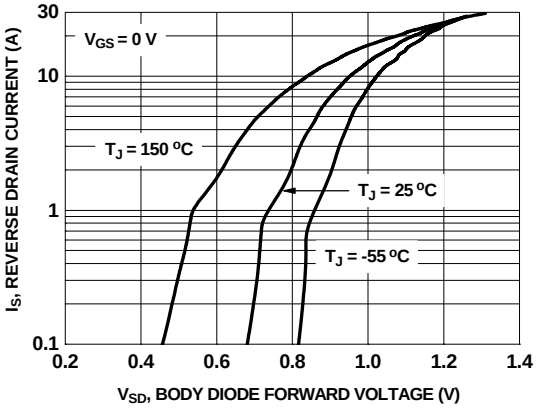

Figure 6. Source to Drain Diode Forward Voltage vs Source Current

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Typical Characteristics T_J = 25°C unless otherwise noted

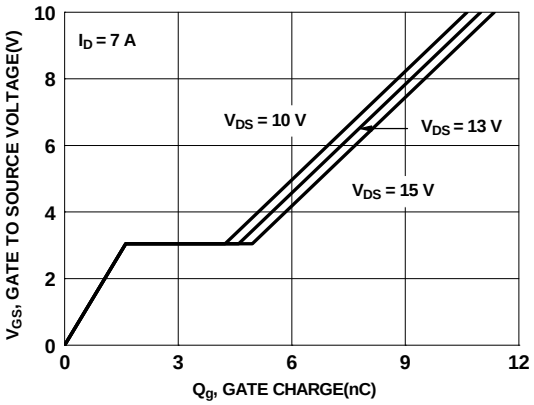

Figure 7. Gate Charge Characteristics

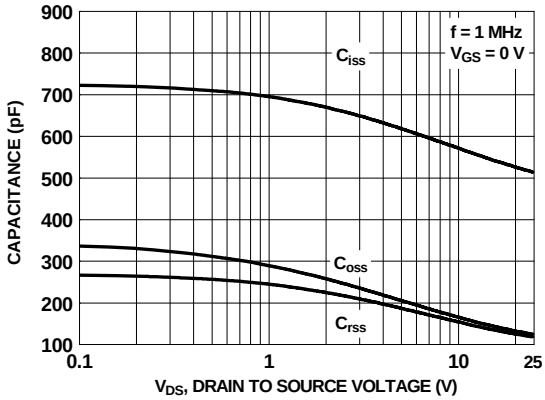

Figure 8. Capacitance vs Drain to Source Voltage

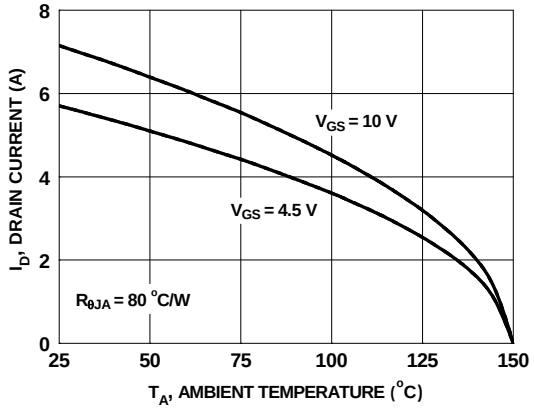

Figure 9. Maximum Continuous Drain Current vs Ambient Temperature

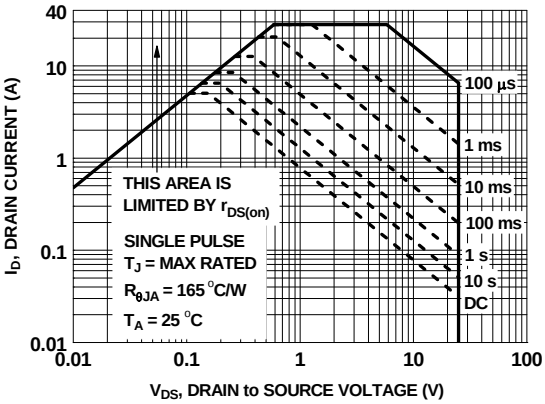

Figure 10. Forward Bias Safe Operating Area

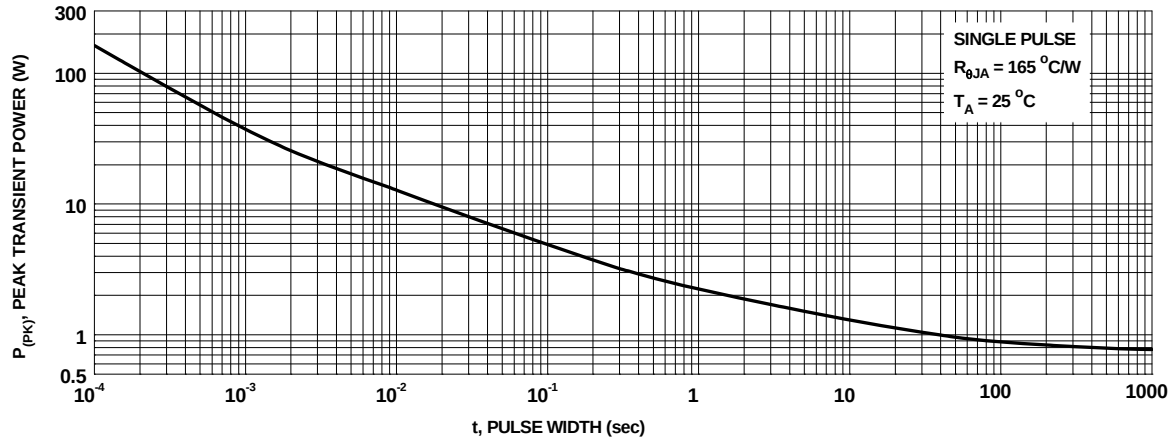

Figure 11. Single Pulse Maximum Power Dissipation

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Typical Characteristics T_J = 25°C unless otherwise noted

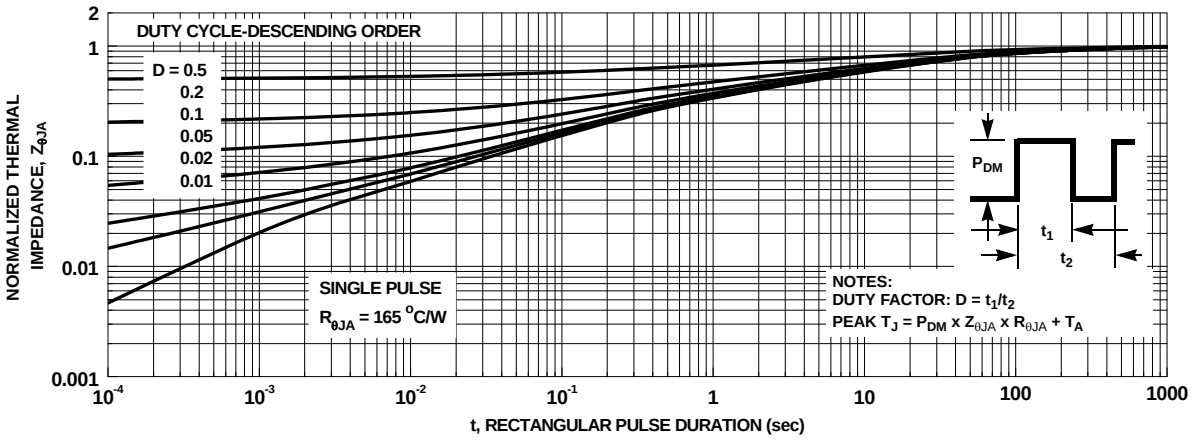

Figure 12. Junction-to-Ambient Transient Thermal Response Curve

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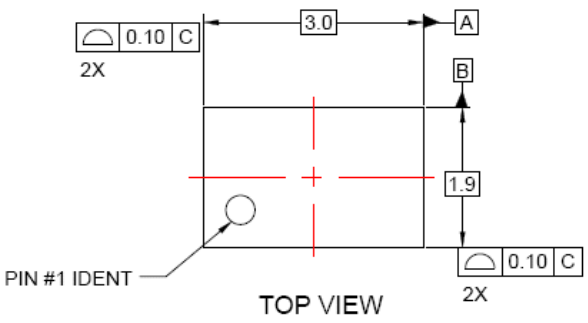
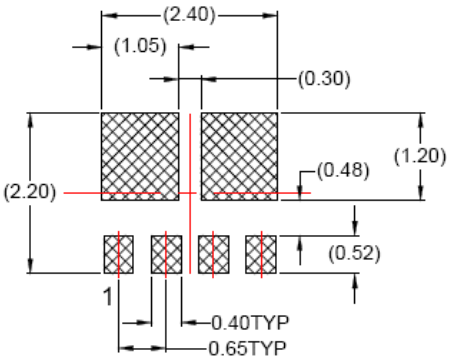
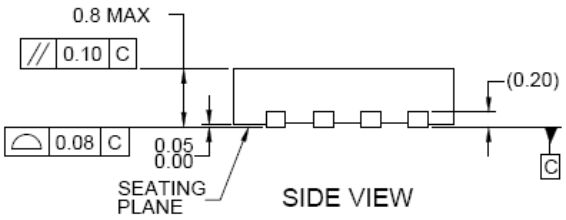
Dimensional Outline and Pad Layout



TOP VIEW



RECOMMENDED LAND PATTERN



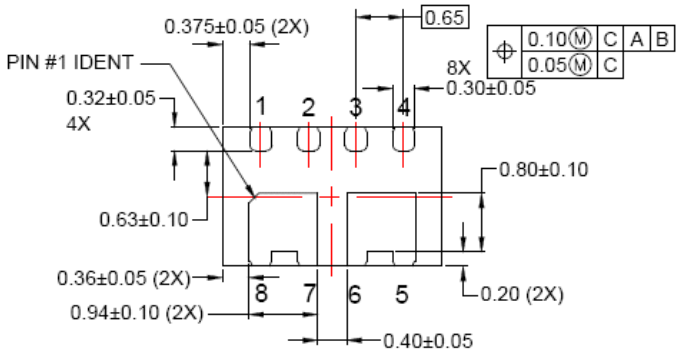
SIDE VIEW

NOTES:

A. DOES NOT FULLY CONFORM TO JEDED REGISTRATION MO-229.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 2009.



BOTTOM VIEW

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